FORM PTO-1449			Docket Number (Optional) 88519.0003		Application Number Not assigned	
INFORMATION DISCLOSURE CITATION IN AN APPLICATION (Use several sheets if necessary)			Applicant Ken NAKAHARA			
			Filing Date February 4, 2004		Group Art Unit Not assigned	
		U.S. PATEN	T DOCUMENTS			
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
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	FO	REIGN PATI	ENT DOCUMENTS			
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION (YES/NO)
Me	2002-118330	04/19/02	Japan			Abstract
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	OTHER DOCUMENTS	S (including Au	thor, Title, Date, Perti	inent Pages,	Etc.)	
Soon-Ku Hong et al., "Control of polarity of ZnO films grown by plasma-assisted molecular-beam epitaxy: Zn- and O-polar ZnO films on Ga-polar GaN templates", Applied Physics Letters, Vol. 77, No. 22, November 27, 2000, pp. 3571-3573						
1/	D.C. Look et al., "Characterization of homoepitaxial p-type ZnO grown by molecular beam epitaxy", Applied Physics Letters, Vol. 81, No. 10, September 2, 2002, pp. 1830-1832.					
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EXAMINER: In conformance	nitial if citation considered, whether or rand not considered. Include copy of the	not citation is in is form with nex	conformance with MPE t communication to the	EP § 609; Drav applicant.	v line through ci	tation if not in